



Product/Process Change Notice - PCN 23_0182 Rev. -

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This notice is to inform you of a change that will be made to certain ADI products (see Appendix A) that you may have purchased in the last 2 years. **Any inquiries or requests with this PCN (additional data or samples) must be sent to ADI within 30 days of publication date.** ADI contact information is listed below.

PCN Title:	Notification of Qualification of Pillar Size Update for LT3977, LT3978, LT8636, LT8637, LT8640S, LT8640S-2, LT8643S, LT8643S-2
Publication Date:	15-Sep-2023
Effectivity Date:	18-Dec-2023 <i>(the earliest date that a customer could expect to receive changed material)</i>
Revision Description:	Initial Release.

Description Of Change:

Updating pillar diameter from 85um to 100um.

Reason For Change:

To improve manufacturability.

Impact of the change (positive or negative) on fit, form, function & reliability:

No change in fit, form, function & reliability of the product.

Product Identification *(this section will describe how to identify the changed material)*

The product will be identified from the cut-off date code. A cut-off date code will be provided upon request from the customer.

Summary of Supporting Information:

Qualification has been performed per AEC-Q100, Stress Test Qualification for Integrated Circuits. See attached Qualification Results Summary.

Supporting Documents

Attachment 1: Type: Qualification Results Summary

[ADI_PCN_23_0182_Rev_-LT8640S_Qualification_Report.pdf...](#)

Attachment 2: Type: Delta Qualification Matrix

[ADI_PCN_23_0182_Rev_-PCN-Delta-Qualification-Matrix-ZVEI_20230828.xls...](#)

Note: If applicable, the device material declaration will be updated due to material change.

ADI Contact Information:

For questions on this PCN, please send an email to the regional contacts below or contact your local ADI sales representatives.

Americas:	Europe:	Japan:	Rest of Asia:
PCN_Americas@analog.com	PCN_Europe@analog.com	PCN_Japan@analog.com	PCN_ROA@analog.com

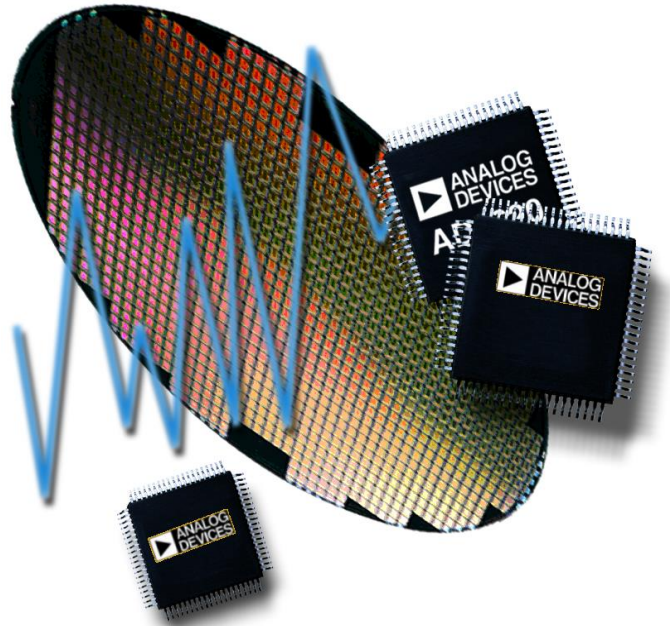
Appendix A - Affected ADI Models:

Added Parts On This Revision - Product Family / Model Number (75)

LT3977 / LT3977EV#PBF	LT3977 / LT3977EV#WVPBF	LT3977 / LT3977JV#PBF	LT3977 / LT3977JV#WVPBF	LT3978 / LT3978EV#PBF
LT3978 / LT3978EV#WVPBF	LT3978 / LT3978JV#3ZZPBF	LT3978 / LT3978JV#PBF	LT3978 / LT3978JV#WVPBF	LT8636 / LT8636EV#PBF
LT8636 / LT8636EV#TRMPBF	LT8636 / LT8636EV#TRPBF	LT8636 / LT8636EV#WVPBF	LT8636 / LT8636HV#3ZZPBF	LT8636 / LT8636HV#3ZZTRPBF
LT8636 / LT8636HV#PBF	LT8636 / LT8636HV#TRMPBF	LT8636 / LT8636HV#TRPBF	LT8636 / LT8636HV#WVPBF	LT8636 / LT8636HV#WTRPBF
LT8636 / LT8636JV#PBF	LT8636 / LT8636JV#TRMPBF	LT8636 / LT8636JV#TRPBF	LT8636 / LT8636JV#WVPBF	LT8636 / LT8636JV#WTRPBF
LT8636 / LT8636MPV#PBF	LT8636 / LT8636MPV#TRPBF	LT8637 / LT8637EV#PBF	LT8637 / LT8637EV#TRMPBF	LT8637 / LT8637EV#TRPBF
LT8637 / LT8637EV#WVPBF	LT8637 / LT8637JV#PBF	LT8637 / LT8637JV#TRMPBF	LT8637 / LT8637JV#TRPBF	LT8637 / LT8637JV#WVPBF
LT8640S / LT8640SEV#PBF	LT8640S / LT8640SEV#TRPBF	LT8640S / LT8640SEV#WVPBF	LT8640S / LT8640SEV#WTRPBF	LT8640S / LT8640SIV#PBF
LT8640S / LT8640SIV#TRPBF	LT8640S / LT8640SIV#WVPBF	LT8640S / LT8640SIV#WTRPBF	LT8640S-2 / LT8640SEV-2#PBF	LT8640S-2 / LT8640SEV-2#TRPBF
LT8640S-2 / LT8640SHV-2#3ZZPBF	LT8640S-2 / LT8640SHV-2#3ZZTRPBF	LT8640S-2 / LT8640SHV-2#PBF	LT8640S-2 / LT8640SHV-2#TRPBF	LT8640S-2 / LT8640SHV-2#WVPBF
LT8640S-2 / LT8640SHV-2#WTRPBF	LT8640S-2 / LT8640SIV-2#3MOPBF	LT8640S-2 / LT8640SIV-2#3ZZPBF	LT8640S-2 / LT8640SIV-2#PBF	LT8640S-2 / LT8640SIV-2#TRPBF
LT8640S-2 / LT8640SIV-2#WVPBF	LT8640S-2 / LT8640SIV-2#WTRPBF	LT8643S / LT8643SEV#PBF	LT8643S / LT8643SEV#TRPBF	LT8643S / LT8643SEV#WVPBF
LT8643S / LT8643SEV#WTRPBF	LT8643S / LT8643SIV#PBF	LT8643S / LT8643SIV#TRPBF	LT8643S / LT8643SIV#WVPBF	LT8643S / LT8643SIV#WTRPBF
LT8643S-2 / LT8643SEV-2#PBF	LT8643S-2 / LT8643SEV-2#TRPBF	LT8643S-2 / LT8643SHV-2#PBF	LT8643S-2 / LT8643SHV-2#TRPBF	LT8643S-2 / LT8643SHV-2#WVPBF
LT8643S-2 / LT8643SHV-2#WTRPBF	LT8643S-2 / LT8643SIV-2#PBF	LT8643S-2 / LT8643SIV-2#TRPBF	LT8643S-2 / LT8643SIV-2#WVPBF	LT8643S-2 / LT8643SIV-2#WTRPBF

Appendix B - Revision History:

Rev	Publish Date	Effectivity Date	Rev Description
Rev. -	15-Sep-2023	18-Dec-2023	Initial Release.



Reliability Report

Report Title: LT8640S Assembly Process Change
Automotive Grade 1 Qualification

Report Number: 20149

Revision: B

Date: July 20, 2023

Summary

This report documents the successful completion of the automotive reliability qualification requirements for the release of the LT8640S product in a 24-LGA package. The LT8640S is a 42V, 6A Synchronous Step-Down Silent Switcher 2 with 2.5uA Quiescent Current.

AECQ100 Qualification Test Methods and Summary

AEC Test Group	AEC Stress Test Name	Abbreviation	AEC Test #	Reference
Group A ACCELERATED ENVIRONMENT STRESS TESTS	Preconditioning	PC	A1	Table 2 and Table 4
	Temperature Humidity Bias or Biased-HAST	THB or HAST	A2	
	Autoclave or Unbiased HAST or Temperature Humidity (without Bias)	AC, UHST, or TH	A3	
	Temperature Cycle	TC	A4	
	Power Temperature Cycling	PTC	A5	
	High Temperature Storage Life	HTSL	A6	
Group B ACCELERATED LIFETIME SIMULATION TESTS	High Temperature Operating Life	HTOL	B1	Table 2 and Table 4
	Early Life Failure Rate	ELFR	B2	
	NVM Endurance, Data Retention, and Operational Life	EDR	B3	
Group C PACKAGE ASSEMBLY INTEGRITY TESTS	Wire Bond Shear	WBS	C1	C1, C2 are only applicable for wire bond package. C5 is only applicable for BGA package. C3, C4 and C6 are qualified and controlled with inline monitors and may be viewed on site at Analog Devices.
	Wire Bond Pull Strength	WBP	C2	
	Solderability	SD	C3	
	Physical Dimensions	PD	C4	
	Solder Ball Shear	SBS	C5	
	Lead Integrity	LI	C6	
Group D DIE FABRICATION RELIABILITY TESTS	Electromigration	EM	D1	Die Fabrication Reliability data may be viewed on-site at Analog Devices.
	Time Dependent Dielectric Breakdown	TDDB	D2	
	Hot Carrier Injection	HCI	D3	
	Negative Bias Temperature Instability	BTI	D4	
	Stress Migration	SM	D5	
Group E ELECTRICAL VERIFICATION TESTS	Pre- and Post-Stress Electrical Test	TEST	E1	Table 5 and Table 6
	Electrostatic Discharge Human Body Model	HBM	E2	
	Electrostatic Discharge Charged Device Model	CDM	E3	
	Latch-Up	LU	E4	<ul style="list-style-type: none"> • For Tests E5, E6 and E7, ADI New Product Yield Analysis Testing Guidelines meet AEC Q100 requirements. • Results for Tests E7-E11 are available as applicable on a case by case basis. • Test E12 results may be viewed on-site at Analog Devices
	Electrical Distributions	ED	E5	
	Fault Grading	FG	E6	
	Characterization	CHAR	E7	
	Electromagnetic Compatibility	EMC	E9	
	Short Circuit Characterization	SC	E10	
	Soft Error Rate	SER	E11	
	Lead (Pb) Free	LF	E12	
	Group F DEFECT SCREENING TESTS	Process Average Test	PAT	
Statistical Bin/Yield Analysis		SBA	F2	
Group G CAVITY PACKAGE INTEGRITY TESTS	Mechanical Shock	MS	G1	<Applicable only for Cavity Packages>
	Variable Frequency Vibration	VFV	G2	
	Constant Acceleration	CA	G3	
	Gross/Fine Leak	GFL	G4	
	Package Drop	DROP	G5	
	Lid Torque	LT	G6	
	Die Shear	DS	G7	
	Internal Water Vapor	IWV	G8	

Die/Fab Product Characteristics
Table 1: Die/Fab Product Characteristics- 0.35µm DMOS

Product Characteristics	Product(s) to be qualified	Product(s) used for Substitution Data			
Generic/Root Part #	LT8640S	LT8685S	LT8650S/SP	LT8648S	LT8686S
Die Id	8640-6	8685	8650-4	8648	8686
Die Size (mm)	1.66 x 2.83	1.7x4.06	1.75 x 3.88	6.2x2.7	3.2 x 1.75
Wafer Fabrication Site	Vanguard	Vanguard	Vanguard	Vanguard	Vanguard
Wafer Fabrication Process	0.35µm DMOS	0.35µm DMOS	0.35µm DMOS	0.35µm DMOS	0.35µm DMOS
Metallization / # Layers	AlCu / 3	AlCu / 3	AlCu / 3	AlCu / 3	AlCu / 3
Polyimide	No	No	No	No	No
Passivation	oxide/SiN	oxide/SiN	oxide/SiN	oxide/SiN	oxide/SiN

Die/Fab Test Results
Table 2: Die/Fab Test Results - 0.35µm DMOS at Vanguard

Test Name	AEC #	Spec	Conditions	Generic/Root Part #	Lot #	Fail/SS	Test Temp.
Early Life Failure Rate (ELFR)	B6	AEC-Q100- 008	Ta=150°C, 48 Hours	LT8650SP	Q17503.1ELFR	0/800	RH
					Z51176.1	0/800	RH
				LT8648S	EO9353.ELFR	0/800	RH
					Z48440.1	0/800	RH
				LT8648SP	Z50105.1	0/800	RH
High Temperature Operating Life (HTOL)	B1	JESD22- A108	Ta=150°C, Biased, 1,000 hours	LT8686S	Q17405.1BHTOL	0/77	RHC
					Q17405.2HTOL	0/77	RHC
					Q20395.1HTOL	0/77	RHC
				LT8640S-2	Q17089.1HTOL	0/77	RHC
					Q17089.2HTOL	0/77	RHC
				Q17089.3HTOL	0/77	RHC	
			LT8685S	Q17750.1HTOL	0/77	RHC	
			LT8650S-1	Q16719.1HTOL	0/77	RHC	
				Q16719.3HTOL	0/77	RHC	
			LT8650SP	Q17503.1HTOL	0/77	RHC	
				965461.1	0/77	RHC	
			Ta=125°C, Biased, 1,000 hours	LT8640S	Q20149.1HTOL	0/77	RHC
			High Temperature Storage Life (HTSL)	A6	JESD22- A103	150°C, 2,000 Hours	LT8648S
LT8686S	Q17405.1HTS	0/45					RH
LT8650SP	EO9392F.HTS	0/45					RH
150°C, 1,000 hours	LT8640S	EO9270F.HTS				0/45	RH
Highly Accelerated Temperature and Humidity Stress Test (HAST) ¹	A2	JESD22- A110	130°C 85%RH 33.3 psia, Biased, 192 Hours	LT8650SP	EO9392K.BHAST	0/77	RH
					EO9413K.BHAST	0/77	RH
					EO9483K.BHAST	0/77	RH
					Q17503.1BHAST	0/77	RH
				LT8650S	EO9372K.BHAST	0/77	RH
				LT8648S	EO9237K.BHAST	0/77	RH
			130°C 85%RH 33.3 psia, Biased, 96 Hours	LT8686S	Q17405.1BHAST	0/77	RH
					Q20395.1HAST	0/77	RH
				LT8648S	EO9508K.BHAST	0/77	RH
					EO9353K.BHAST	0/77	RH
				LT8640S	Q20149.1HAST	0/77	RH
					Q20149.2HAST	0/77	RH

¹ These samples were subjected to preconditioning at MSL 3 with 3x reflow peak temp of 260°C prior to the start of the stress test.

Package/Assembly Product Characteristics

Table 3: Package/Assembly Product Characteristics - LGA at ASE

Product Characteristics	Product(s) to be qualified	Product(s) used for Substitution Data			
Generic/Root Part #	LT8640S	LT8645S	LT8646S	LT8642S/-2	LT8642-1
Package	24-LGA	32-LGA	32-LGA	24-LGA	20-LGA
Body Size (mm)	4 x 4 x 0.94	6.00 x 4.00 x 0.94	6.00 x 4.00 x 0.94	4.00 x 4.00 x 0.94	4.00 x 3.00 x 0.94
Assembly Location	ASE	ASE	ASE	ASE	ASE
MSL/Peak Reflow Temperature (°C)	3 / 260°C	3 / 260°C	3 / 260°C	3 / 260°C	3 / 260°C
Mold Compound	Sumitomo E670E	Sumitomo E670E	Sumitomo E670E	Sumitomo E670E	Sumitomo E670E
Leadframe Material	BT Resin	BT Resin	BT Resin	BT Resin	BT Resin
Lead Finish	Au	Au	Au	Au	Au
Bumping Foundry	Chipbond	Chipbond	Chipbond	Chipbond	Chipbond
Bumping Process	Electroplating/ Cu Pillar	Electroplating/ Cu Pillar	Electroplating/ Cu Pillar	Electroplating/ Cu Pillar	Electroplating/ Cu Pillar
Bump Pitch (mm)	0.155	0.165	0.165	0.155	0.155
Bump Diameter (mm)	0.100	0.100	0.085	0.085	0.085

Package/Assembly Test Results
Table 4: Package/Assembly Test Results - LGA at ASE

Test Name		Spec	Conditions	Generic/Root Part #	Lot #	Fail/SS	Test Temp		
High Temperature Storage Life (HTSL)	A6	JESD22-A103	150°C, 1,000 Hours	LT8640S	EO9270F.HTS	0/45	RH		
				LT8645S	EO9223F.HTS	0/45	RH		
				LT8646S	EO9236F.HTS	0/45	RH		
				LT8642-1	Q18281.1HTS	0/45	RH		
Highly Accelerated Temperature and Humidity Stress Test (HAST) ¹	A2	JESD22-A110	130°C 85%RH 33.3 psia, Biased, 192 Hours	LT8646S	EO9236K.BHAST	0/77	RH		
				LT8645S	EO9223K.BHAST	0/77	RH		
				EO9224K.BHAST	0/77	RH			
			130°C 85%RH 33.3 psia, Biased, 96 Hours	LT8640S	Q20149.1HAST	0/77	RH		
				Q20149.2HAST	0/77	RH			
				LT8642-1	Q18281.1BHAST	0/77	RH		
		Q18281.2BHAST	0/77	RH					
		Q18281.3BHAST	0/77	RH					
		LT8642-2	Q17089.1BHAST	0/77	RH				
		Temperature Cycling (TC) ¹	A4	JESD22-A104	-65°C/+150°C, 500 Cycles	LT8642-1	Q18281.1TC	0/77	RH
Q18281.2TC	0/77					RH			
Q18281.3TC	0/77					RH			
-65°C/+150°C, 1,000 Cycles	LT8640S				EO9270B.TC	0/77	RH		
	LT8642-2				Q17089.TC1	0/77	RH		
	LT8646S				EO9236B.TC	0/77	RH		
-65°C/+150°C, 1500 Cycles	LT8645S			EO9223B.TC	0/77	RH			
				EO9224B.TC	0/77	RH			
				Q20149.1TC	0/77	RH			
-65°C/+150°C, 2000 Cycles	LT8640S			Q20149.2TC	0/77	RH			
Unbiased HAST (UHST) ¹				JESD22-A118	130°C 85%RH 33.3 psia, 96 Hours	LT8642-1	Q18281.1UHAST	0/77	R
							Q18281.2UHAST	0/77	R
		Q18281.3UHAST	0/77				R		
		LT8645S	EO9223K1.UHST			0/77	R		
			EO9224K1.UHST			0/77	R		
		LT8646S	EO9236K1.UHST			0/77	R		
		LT8640S	EO9270K1.UHAST			0/77	R		
		LT8642-2	Q17089.UH1			0/77	R		

¹ These samples were subjected to preconditioning at MSL 3 with 3x reflow peak temp of 260°C prior to the start of the stress test.

ESD and Latch-Up Test Results

Table 5: ESD Test Results

ESD Model	Generic/Root Part #	Package	ESD Test Spec	RC Network	Highest Pass Level	Class
FICDM	LT8640S	24-LGA	JS-002	1Ω, Cpkg	±2000V	C3
HBM	LT8640S	24-LGA	ESDA/JEDEC JS-001	1.5kΩ, 100pF	±4000V	3A

Table 6: Latch Up Test Result

LU Test Spec	Generic/Root Part #	Passing Current	Temperature (Ta)	Class
JESD78	LT8640S	-100mA, +100mA	125°C	II

Approvals

Reliability Engineer: Hang Luu